

Features

- 1.4 INCH MATRIX HEIGHT.
- DOT SIZE 3mm.
- LOW CURRENT OPERATION.
- HIGH CONTRAST AND LIGHT OUTPUT.
- COMPATIBLE WITH ASCII AND EBCDIC CODES.
- STACKABLE HORIZONTALLY AND VERTICALLY.
- COLUMN CATHODE AND COLUMN ANODE AVAILABLE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- CATEGORIZED FOR LUMINOUS INTENSITY, YELLOW AND GREEN CATEGORIZED FOR COLOR.
- MECHANICALLY RUGGED.
- STANDARD: GRAY FACE, WHITE DOT.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

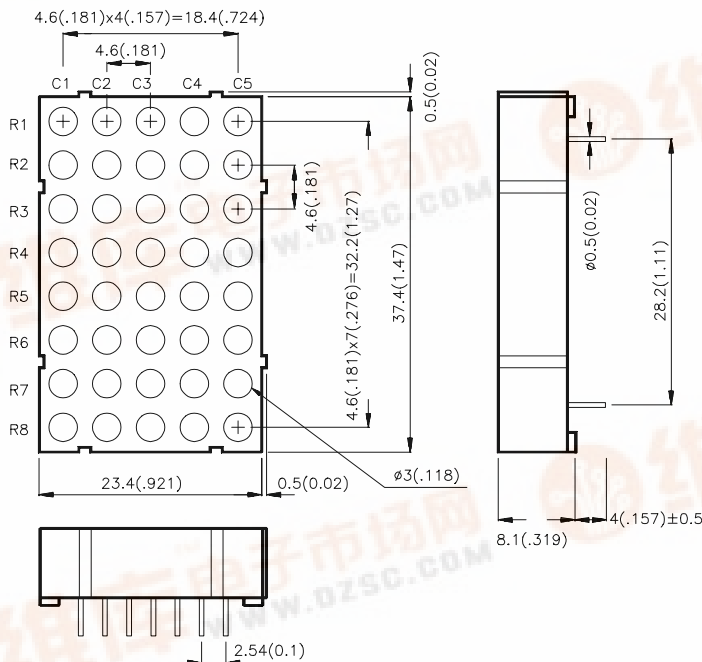
The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

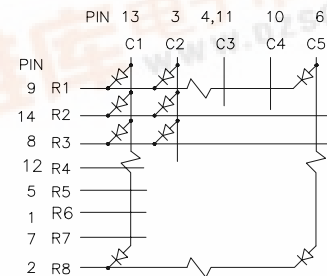
The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram

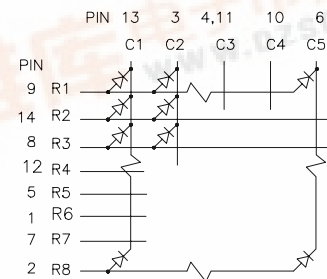
TA/TC16-11



TA16-11



TC16-11



Notes:

1. All dimensions are in millimeters (inches). Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Iv (ucd) @ 10 mA		Description
		Min.	Typ.	
TA16-11EWA	HIGH EFFICIENCY RED (GaAsP/GaP)	3000	8000	Column Anode
TC16-11EWA				Column Cathode
TA16-11GWA	GREEN (GaP)	4700	12000	Column Anode
TC16-11GWA				Column Cathode
TA16-11YWA	YELLOW (GaAsP/GaP)	1900	4700	Column Anode
TC16-11YWA				Column Cathode
TA16-11SRWA	SUPER BRIGHT RED (GaAlAs)	8000	24000	Column Anode
TC16-11SRWA				Column Cathode

Electrical / Optical Characteristics at T_A=25°C

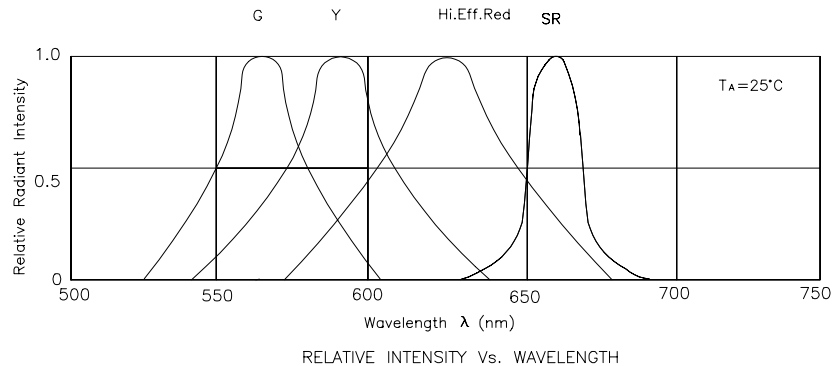
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red Green Yellow Super Bright Red	627 565 590 660		nm	IF=20mA
λ_D	Dominate Wavelength	High Efficiency Red Green Yellow Super Bright Red	625 568 588 640		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Halfwidth	High Efficiency Red Green Yellow Super Bright Red	45 30 35 20		nm	IF=20mA
C	Capacitance	High Efficiency Red Green Yellow Super Bright Red	15 15 20 45		pF	VF=0V;f=1MHz
V _F	Forward Voltage	High Efficiency Red Green Yellow Super Bright Red	2.0 2.2 2.1 1.85	2.5 2.5 2.5 2.5	V	IF=20mA
I _R	Reverse Current	All		10	uA	VR = 5V

Absolute Maximum Ratings at $T_A=25^\circ\text{C}$

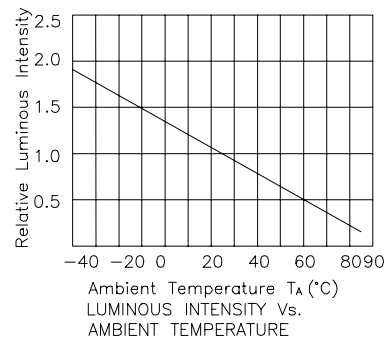
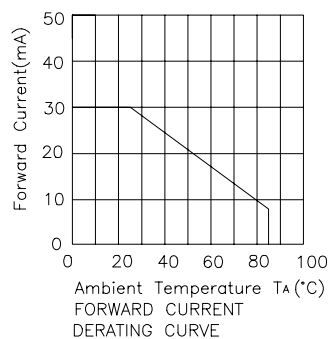
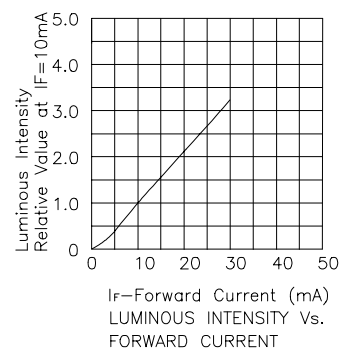
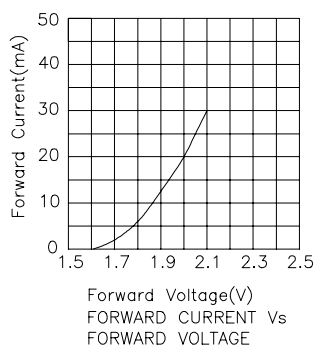
Parameter	Bright Red	High Efficiency Red	Green	Yellow	Super Bright Red	Units
Power dissipation	120	105	105	105	100	mW
DC Forward Current	25	30	25	30	30	mA
Peak Forward Current [1]	150	150	150	150	150	mA
Reverse Voltage	5	5	5	5	5	V
Operating/Storage Temperature	-40°C To $+85^\circ\text{C}$					
Lead Soldering Temperature [2]	260°C For 5 Seconds					

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 4mm below package base.

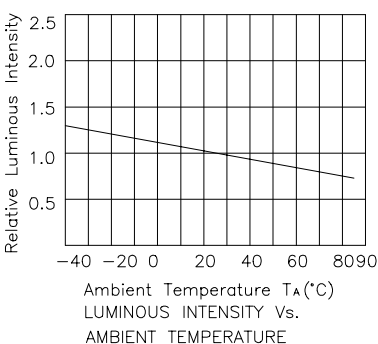
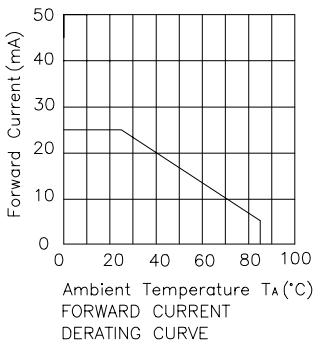
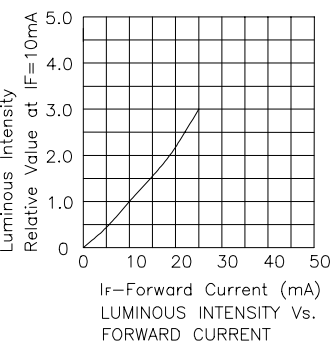
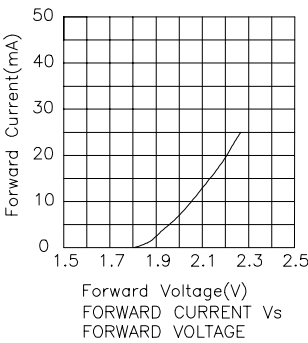


High Efficiency Red

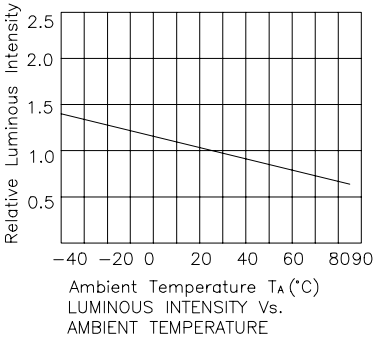
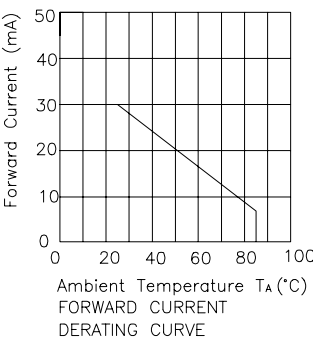
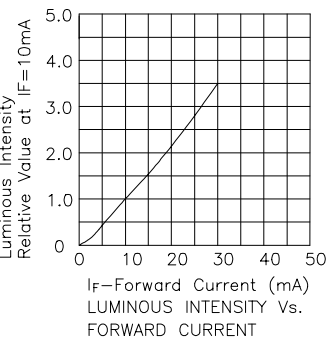
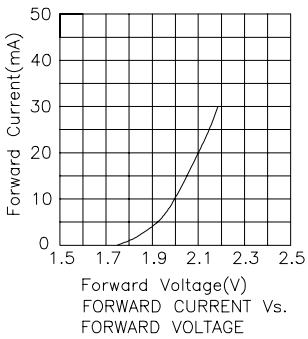


Kingbright

Green



Yellow



Kingbright

Super Bright Red

